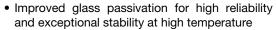


Medium Power Phase Control Thyristors (Stud Version), 10 A



PRODUCT SUMMARY				
Package	TO-208AA (TO-48)			
Diode variation	Single SCR			
I _{T(AV)}	10 A			
V _{DRM} /V _{RRM}	100 V to 1200 V			
V _{TM}	1.75 V			
I _{GT}	60 mA			
T _J	-65 °C to 125 °C			

FEATURES





- High dI_F/dt and dV/dt capabilities
- Standard package
- · Low thermal resistance
- · Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- Designed and qualified for industrial and consumer level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- · Medium power switching
- Phase control applications
- Can be supplied to meet stringent military, aerospace and other high reliability requirements

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
1		10	A	
I _{T(AV)}	T _C	85	°C	
I _{T(RMS)}		25	A	
I _{TSM}	50 Hz	225	Α	
	60 Hz	240		
l²t	50 Hz	255	42-	
	60 Hz	233	— A ² s	
V _{DRM} /V _{RRM}		100 to 1200	V	
t _q	Typical	110	μs	
TJ		-65 to 125	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	I_{DRM}/I_{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA			
	10	100	150	20			
	20	200	300				
	40	400	500				
VS-10RIA	60	600	700	10			
	80	800	900	10			
	100	1000	1100				
	120	1200	1300				

Notes

⁽¹⁾ Units may be broken over non-repetitively in the off-state direction without damage, if dl/dt does not exceed 20 A/µs

 $[\]ensuremath{^{(2)}}$ For voltage pulses with $t_p \leq 5 \ ms$



ABSOLUTE MAXIMUM RAT	rings					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current	l=	180° conducti	on, half sine wave		10	Α
at case temperature	I _{T(AV)}	100 Conducti	on, nan sine wave		85	°C
Maximum RMS on-state current	I _{T(RMS)}				25	Α
		t = 10 ms	No voltage		225	
Maximum peak, one-cycle	L	t = 8.3 ms	reapplied		240	Α
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		190	^
		t = 8.3 ms	reapplied	Sinusoidal half wave,	200	1
Maximum I ² t for fusing		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	255	- A ² s
	l ² t	t = 8.3 ms	reapplied		233	
	1-1	t = 10 ms	100 % V _{RRM}		180	
		t = 8.3 ms	reapplied		165	
Maximum I $^2\sqrt{t}$ for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied		2550	A²√s	
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum		1.10	V	
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)}),$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		1.39	v
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum		24.3	mΩ	
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		16.7	11152	
Maximum on-state voltage	V_{TM}	$I_{pk} = 32 \text{ A}, T_J = 25 ^{\circ}\text{C}, t_p = 10 \text{ ms sine pulse}$		1.75	V	
Maximum holding current	I _H	·		130	mΛ	
Typical latching current	ΙL	1j = 25 C, an	$T_J = 25$ °C, anode supply 12 V resistive load		200	mA

SWITCHING					
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS
	$V_{DRM} \le 600 \text{ V}$			200	
Maximum rate of rise	$V_{DRM} \le 800 \text{ V}$	dl₅/dt	$T_J = T_J$ maximum, $V_{DM} = Rated V_{DRM}$	180	A/µs
of turned-on current $V_{DRM} \le 100$		uiF/ui	Gate pulse = 20 V, 15 Ω , t_p = 6 μ s, t_r = 0.1 μ s maximum t_{TM} = (2 x rated dl/dt) A	160	Ανμδ
	V _{DRM} ≤ 1600 V			150	
Typical turn-on time		t _{gt}	$T_J = 25$ °C, at rated V_{DRM}/V_{RRM} , $T_J = 125$ °C	0.9	
Typical reverse recovery time		t _{rr}	$T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200~\mu s$, $dI_F/dt = -10~A/\mu s$	4	μs
Typical turn-off time		tq	$T_J=T_J$ maximum, $l_{TM}=l_{T(AV)},t_p>200~\mu s,V_R=100~V,dl_F/dt=$ - 10 A/ $\mu s,dV/dt=20~V/\mu s$ linear to 67 $\%~V_{DRM},$ gate bias 0 V to 100 W	110	μο

Note

• $t_q = 10 \mu s$ up to 600 V, $t_q = 30 \mu s$ up to 1600 V available on special request

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise	dV/dt	$T_J = T_J$ maximum linear to 100 % rated V_{DRM}	100	V/µs
of off-state voltage	uv/ut	$T_J = T_J$ maximum linear to 67 % rated V_{DRM}	300 (1)	ν/μ5

Note

 $^{(1)}$ Available with: $dV/dt = 1000 V/\mu s$, to complete code add S90 i.e. 10RIA120S90



TRIGGERING					
PARAMETER	SYMBOL	TE	ST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}	T - T movimum		8.0	W
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum		2.0	
Maximum peak positive gate current	I_{GM}	$T_J = T_J$ maximum		1.5	Α
Maximum peak negative gate voltage	-V _{GM}	$T_J = T_J$ maximum		10	V
	I _{GT}	T _J = - 65 °C	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied	90	mA
DC gate current required to trigger		T _J = 25 °C		60	
		T _J = 125 °C		35	
	V _{GT}	T _J = - 65 °C		3.0	V
DC gate voltage required to trigger		T _J = 25 °C		2.0	
		T _J = 125 °C		1.0	
DC gate current not to trigger	I_{GD}	T _J = T _J maximum, V _{DRM} = Rated value		2.0	mA
DC gate voltage not to trigger	V_GD	$T_J = T_J$ maximum, $V_{DRM} = Rated value$	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.2	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VAL	VALUES	
Maximum operating junction and storage temperature range	T _J , T _{Stg}		-65 to 125		°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.85		K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased 0.38		35	r\/ vv
			TO NUT	TO DEVICE	
			20 (27.5)	25	lbf · in
Mounting torque		Lubricated threads (Non-lubricated threads)	0.23 (0.32)	0.29	kgf ⋅ m
		(1011)021104104 111104409)	2.3 (3.1)	2.8	N·m
Approximate weight			1	4	g
Approximate weight			0.	49	oz.
Case style		See dimensions - link at the end of datasheet	et TO-208AA (TO-48)		8)

△R _{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.44	0.32		
120°	0.53	0.56		
90°	0.68	0.75	$T_J = T_J$ maximum	K/W
60°	1.01	1.05		
30°	1.71	1.73		

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

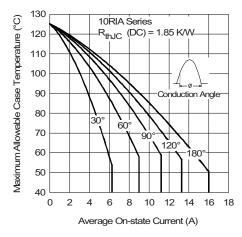


Fig. 1 - Current Ratings Characteristics

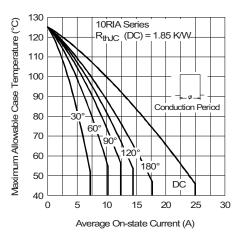


Fig. 2 - Current Ratings Characteristics

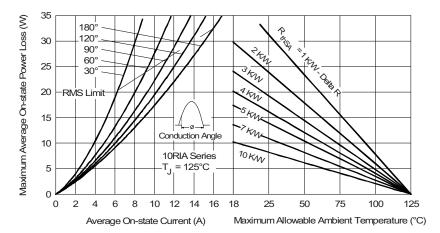


Fig. 3 - On-State Power Loss Characteristics

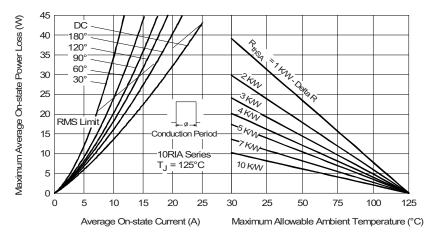


Fig. 4 - On-State Power Loss Characteristics



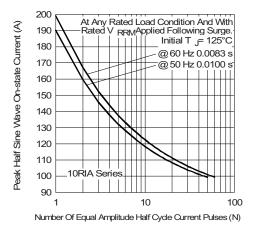


Fig. 5 - Maximum Non-Repetitive Surge Current

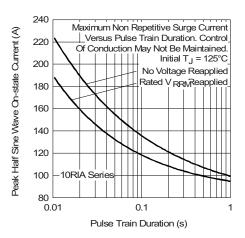


Fig. 6 - Maximum Non-Repetitive Surge Current

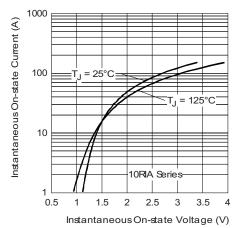


Fig. 7 - Forward Voltage Drop Characteristics

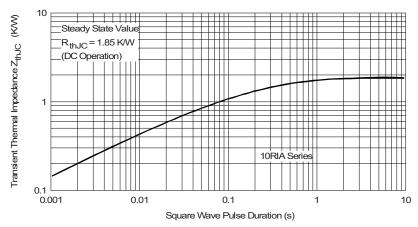


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



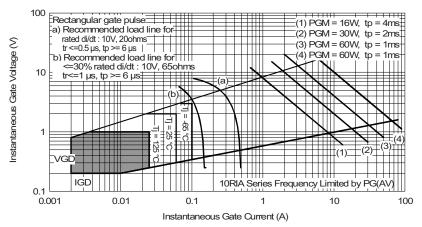
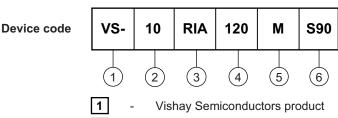


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE



2 - Current code

Essential part number

Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

5 - None = Stud base TO-208AA (TO-48) 1/4" 28UNF-2A

M = Stud base TO-208AA (TO-48) M6 x 1

6 - Critical dV/dt:

None = 300 V/µs (standard value)

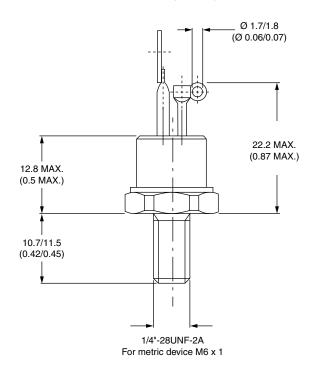
S90 = 1000 V/µs (special selection)

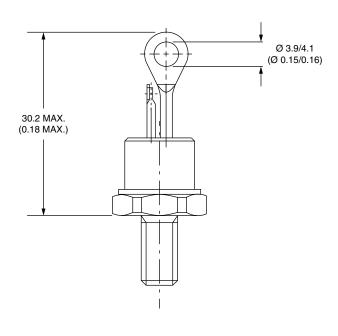
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95333		

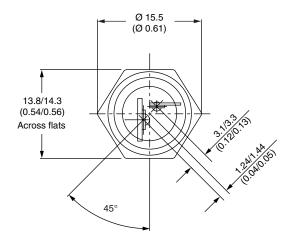


TO-208AA (TO-48)

DIMENSIONS in millimeters (inches)









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Website:

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Contact Us:

> Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com